

PA50 • PA50A

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FEATURES

- HIGH INTERNAL DISSIPATION — 400 Watts
- HIGH CURRENT — 40A Continuous, 100A PEAK
- HIGH SLEW RATE — 50V/ μ s
- OPTIONAL BOOST VOLTAGE INPUTS

APPLICATIONS

- SEMI-CONDUCTOR TESTING

DESCRIPTION

The PA50 is a MOSFET power operational amplifier that extends the performance limits of power amplifiers in slew rate and power bandwidth, while maintaining high current and power dissipation ratings.

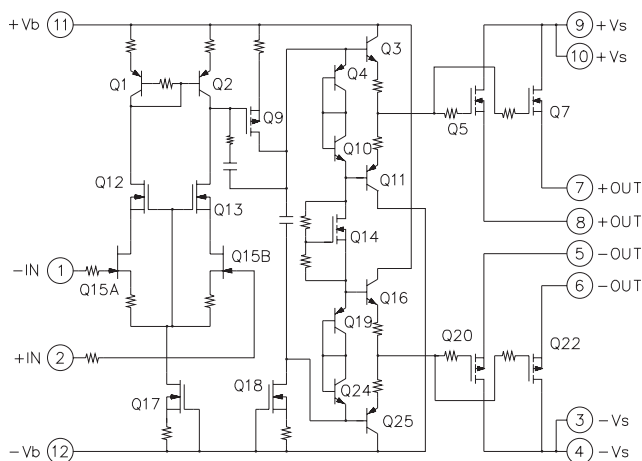
Boost voltage inputs allow the small signal portion of the amplifier to operate at a higher voltage than the high current output stage. The amplifier is then biased to achieve close linear swings to the supply rails at high currents for extra efficient operation.



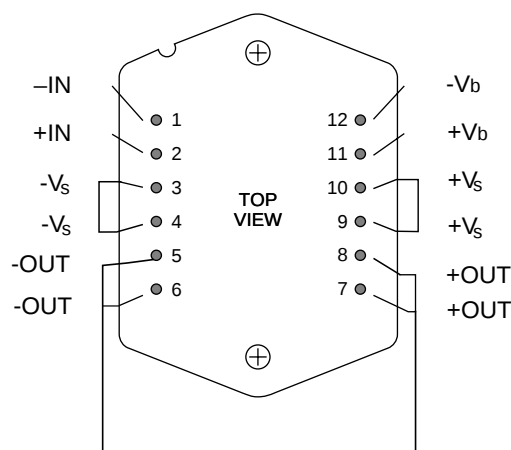
**12-pin DIP
PACKAGE STYLE CR**

The JEDEC MO-127 12-pin Power Dip™ package (see Package Outlines) is hermetically sealed and isolated from the internal circuits. The use of compressible thermal washers and/or improper mounting torque will void the product warranty. Please see "General Operating Considerations".

EQUIVALENT SCHEMATIC



EXTERNAL CONNECTIONS



PA50 • PA50A

ABSOLUTE MAXIMUM RATINGS SPECIFICATIONS

ABSOLUTE MAXIMUM RATINGS

SUPPLY VOLTAGE, $+V_S$ to $-V_S$	100V
BOOST VOLTAGE, $+V_b$ to $-V_b$	130V
OUTPUT CURRENT, within SOA	100A
POWER DISSIPATION, internal	400W
INPUT VOLTAGE, differential	$\pm 20V$
INPUT VOLTAGE, common mode	$\pm V_b$
TEMPERATURE, pin solder - 10s	300°C
TEMPERATURE, junction ²	150°C
TEMPERATURE, storage	-65 to +150°C
OPERATING TEMPERATURE RANGE, case	-55 to +125°C

SPECIFICATIONS

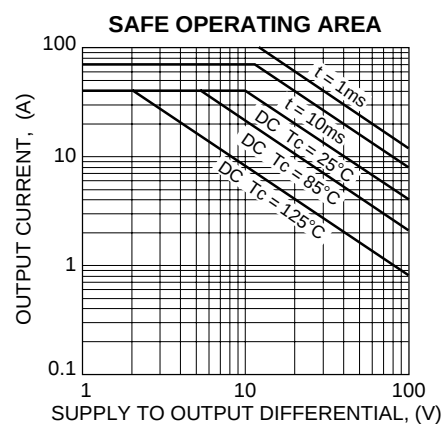
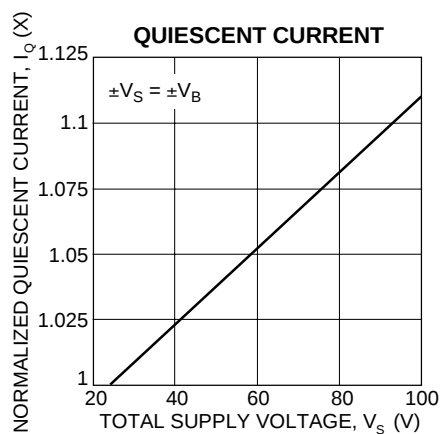
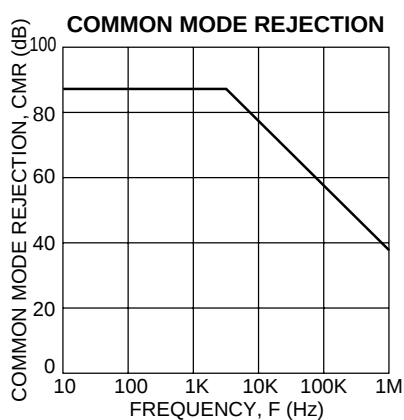
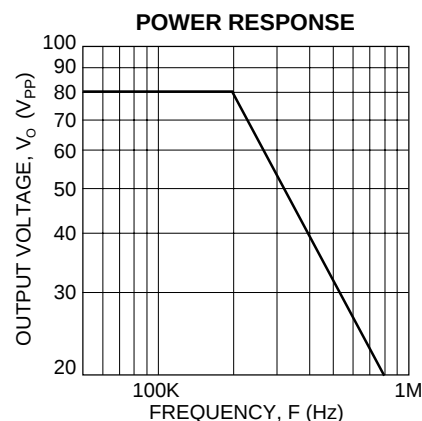
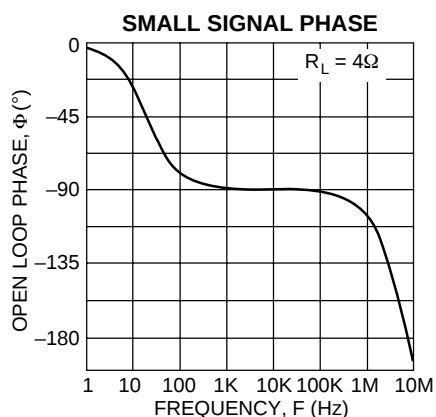
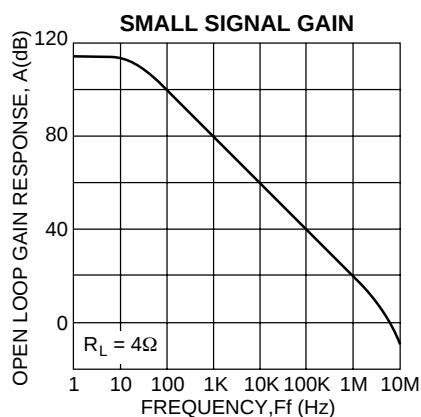
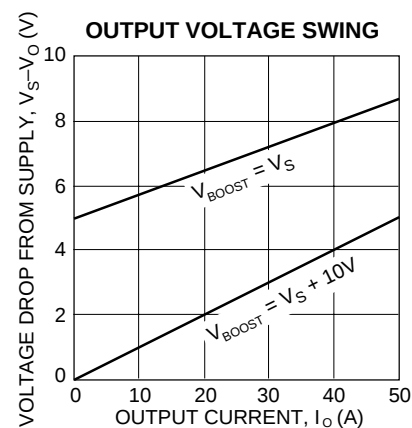
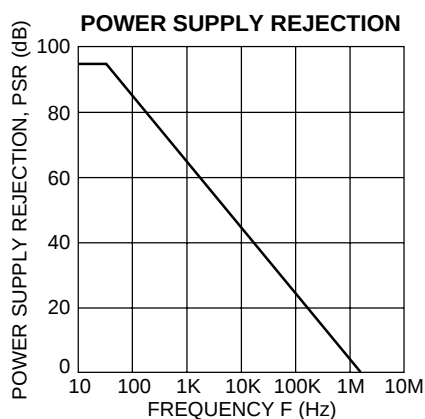
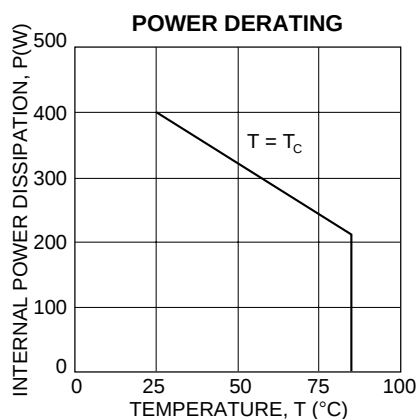
PARAMETER	TEST CONDITIONS ¹	PA50			PA50A			UNITS
		MIN	TYP	MAX	MIN	TYP	MAX	
INPUT								
OFFSET VOLTAGE, initial	Full temperature range		5	10		2	5	mV
OFFSET VOLTAGE, vs. temperature			20	50		*	*	$\mu V/^{\circ}C$
OFFSET VOLTAGE, vs. supply			10	30		*	*	$\mu V/V$
BIAS CURRENT, initial			10	50		*	*	pA
BIAS CURRENT vs. supply			.01			*		pA/V
OFFSET CURRENT, initial	Full temperature range		10	50		*	*	pA
INPUT IMPEDANCE, DC			10"			*		Ω
INPUT CAPACITANCE			13			*		pF
COMMON MODE VOLTAGE RANGE		$-V_B +12$ $+V_B -14$			*			V
COMMON MODE REJECTION, DC		90	100			*	*	dB
INPUT NOISE	Full temp, range, $V_{CM} = \pm 20V$ 100KHZ BW, $R_S = 1K\Omega$		10			*		μV_{rms}
GAIN								
OPEN LOOP, @ 15Hz	Full temperature range	94	102		*	*		dB
GAIN BANDWIDTH PRODUCT	$R_L = 10\Omega$		3			*		MHz
POWER BANDWIDTH	$R_L = 4\Omega$, $V_O = 80V_{P-P}$, $A_v = -10$ Full temperature range		400			*		kHz
OUTPUT								
VOLTAGE SWING	$I_O = 40A$	$\pm V_S \mp 9.5$	$\pm V_S \mp 8.0$		*	*		V
VOLTAGE SWING, PA50	$\pm V_{BOOST} = \pm V_S \pm 10V$, $I_O = 40A$	$\pm V_S \mp 5.8$	$\pm V_S \mp 4.0$					V
VOLTAGE SWING, PA50A	$\pm V_{BOOST} = \pm V_S \pm 10V$, $I_O = 50A$				$\pm V_S \mp 5.8$	$\pm V_S \mp 5.0$		V
CURRENT, peak	3ms 10% Duty Cycle	100			*			A
SETTLING TIME TO 1%	$A_v = -10$, 10V STEP, $R_L = 4\Omega$		1			*		μs
SLEW RATE	$A_v = -10$	50			*			V/ μs
RESISTANCE	$I_O = 0$, NO LOAD, 2MHZ		2.5			*		Ω
POWER SUPPLY								
VOLTAGE, $\pm V_{BOOST}$	Full temperature range	+14, -12	± 15	± 65	*	*	*	V
VOLTAGE, $\pm V_S$	Full temperature range	± 3		± 50	*		*	V
CURRENT, quiescent, boost supply			26	32		*	*	mA
CURRENT, quiescent, total			30	36		*	*	mA
THERMAL								
RESISTANCE, AC, junction to case ³	Full temperature range, $F > 60HZ$		.2	.25		*	*	$^{\circ}C/W$
RESISTANCE, DC, junction to case	Full temperature range, $F > 60HZ$		.25	.31		*	*	$^{\circ}C/W$
RESISTANCE, junction to air	Full temperature range		12			*		$^{\circ}C/W$
TEMPERATURE RANGE, case	Meets full range specification	-25		85	*		*	$^{\circ}C$

- NOTES: *
- The specification of PA50A is identical to the specification for PA50 in applicable column to the left
Unless otherwise noted: $T_C = 25^{\circ}C$, DC input specifications are $\pm$ value given. Power supply voltage is typical rating.
 $\pm V_{BOOST} = \pm V_S$.
 - Long term operation at the maximum junction temperature will result in reduced product life. Derate internal power dissipation to achieve high MTTF. For guidance, refer to the heatsink data sheet.
 - Rating applies if the output current alternates between both output transistors at a rate faster than 60 Hz.

CAUTION

The PA50 is constructed from MOSFET transistors. ESD handling procedures must be observed.

The internal substrate contains beryllia (BeO). Do not break the seal. If accidentally broken, do not crush, machine, or subject to temperatures in excess of 850°C to avoid generating toxic fumes.



GENERAL

Please read Application Note 1 "General Operating Considerations" which covers stability, supplies, heat sinking, mounting, current limit, SOA interpretation, and specification interpretation. Visit www.apexmicrotech.com for design tools that help automate tasks such as calculations for stability, internal power dissipation, current limit; heat sink selection; Apex's complete Application Notes library; Technical Seminar Workbook; and Evaluation Kits.

CURRENT LIMIT

There is no internal circuit provision for current limit in the PA50. However, the PA50 circuit board in the PA50 evaluation kit does provide a means whereby the output current can be sensed. An external circuit current limit can thereby be implemented if needed. See EK27 data sheet for more details.

BOOST OPERATION

With the V_{BOOST} feature the small signal stages of the amplifier are operated at higher supply voltages than the amplifier's high current output stage. $+V_{\text{BOOST}}$ (pin 11) and $-V_{\text{BOOST}}$ (pin 12) are connected to the small signal circuitry of the amplifier. $+V_s$ (pin 9,10) and $-V_s$ (pin 3,4) are connected to the high current output stage. An additional 10V on the V_{BOOST} pins is sufficient to allow the small signal stages to drive the output transistors into saturation and improve the output voltage swing for extra efficient operation when required. When close swings to the supply rails is not required the $+V_{\text{BOOST}}$ and $+V_s$ pins must be strapped together as well as the $-V_{\text{BOOST}}$ and $-V_s$ pins. The boost voltage pins must not be at a voltage lower than the V_s pins.

COMPENSATION

Compensation is internally fixed for a gain of 3 or more and is not adjustable by the user. The PA50 therefore is not unity gain stable.

POWER SUPPLY BYPASSING

Proper and sufficient power supply bypassing is crucial to proper operation of the PA50. Bypass the $+V_b$ and $-V_b$ supply pins with a minimum .1 μ F ceramic capacitors directly at the supply pins. On the $+V_s$ and $-V_s$ pins use a combination of ceramic and electrolytic capacitors. Use 1 μ F ceramic capacitors and an electrolytic capacitor at least 10 μ F for each amp of output current required.